

2) DC Error

One of the things that kills a loudspeaker quickly is a large DC voltage across its input. I've implemented a DC error protection that will engage with DC voltages >6V by disconnecting the amplifier from its power rails and keeping it disconnected until power has been cycled. This way around any faults in the amplifier itself or the fuses failing to blow will not result in additional damage, unless the power supply itself is at fault of course.

I'm relying on the built in over current protection to detect any excess currents flowing due to a shortcircuit, or the amplifier being overdriven.

Anything I missed?



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Quote 2

26th January 2016, 04:47 PM

Alright, one of the tasks still left to do was to calculate the required resistor values for the over current protection. This is largely dependent on the MOSFETs used and the desired maximum SSassen

Join Date: Mar 2005 Location: Beta Zeticuly

In my case I'll be using the IRFB4615 MOSFETs, which have a Rds(on) of 40mOhm and a maximum continuous current of 35A. For the sake of simplicity I'm going to go ahead and set the trip level to 35A.

Referring to the schematic in my previous post, R9 and R10 set the trip current for the low side over current protection (OCP). According to IRF's application note (AN-1138) these can be calculated given the following formula:

Vocset=Itrip*Rds(on) Vocset=35*40mOhm Vocset=1.4V

Vref=5.1V R10=(Vocset/Vref)*10e3 R10=(1.4/5.1)*10e3 R10=2.7kOhm

R9+R10=10k (requirement) R9=10-2.7 R9=7.3k

Closest E12 value is 6.8k, however that means that to meet the R10+R9=10k requirement, R10 will need to be 3.3k. That means Itrip will be different from calculated, so lets see by how

R10=3 3kOhm 3300=(Vocset/5.1)*10e3 0.33=Vocset/5.1 Vocset=1.683V

Itrip=Vocset/Rds(on) Itrip=1.683/0.04 Itrip=42.1A

I guess with a Ipeak of 140A (pulsed drain current) on the IRFB4615, there's some margin (42A is 120% of 35A) so that's acceptable too.

High side current sensing is based on the measurement of Vds (Vdrain-source) across the high side MOSFET during high side turn on through pins CSH and Vs. An external reverse blocking diode, D2, is required to block high voltages from feeding into the CSH pin while the high side is off, hence the forward voltage (Vf) gets added to that voltage.

We'll set the high side over current trip point to the same value as we've set the low side over current trip point. To set the high side over current protection resistor values R11 and R12 need to be calculated given:

R11+R12=10k (requirement) Vthoch=threshold voltage over current high side Vthoch=1.2V Vds=drain-source voltage at Itrip Vf=forward voltage of D2

R12=10e3*(Vthoch/Vds+Vf) Vds=Itrip*Rds(on) Vds=42*0 04

Vds=1.68V (same as Vds on the low side!) Vf=0.6V

R12=10e3*(1.2/1.68+0.6) R12=10e3*0.526 R12=5.3kOhm

R11 = 10 - 5.3

Picking E12 values, we'll select 5.6kOhm for R12 and 4.7kOhm for R11. This will set the Itrip for the high side to 38A, that's 90% of the low side overcurrent trip point, so I guess that's

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The next item on the list is selecting the dead-time setting.



26th January 2016, 06:16 PM



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The IRS2092 comes with a range of preset dead-time settings, which can be selected using a combination of resistors, R13 and R14 in this case. The selection available is between 25 and 105ns. From looking at the various IRF reference designs, and some of the suggestions in the application notes, the DT2 option, 45ns, seems to be the most used setting, resulting in 8.2kOhm for R14 and 3.3kOhm for R13.

I'm going to assume that's safe to use, as any additional dead-time can be added by gate stopper resistors with the defacto diodes over them. Or, when needed, a different selection for R13/R14.

Thoughts?

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Last edited by SSassen; 26th January 2016 at 06:19 PM. Reason: Spelling and grammar.



28th January 2016, 08:55 AM

Join Date: Mar 2011 Location: RF 33 Vladimir

Quote

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#99

Dimonis diyAudio Member

Quote:

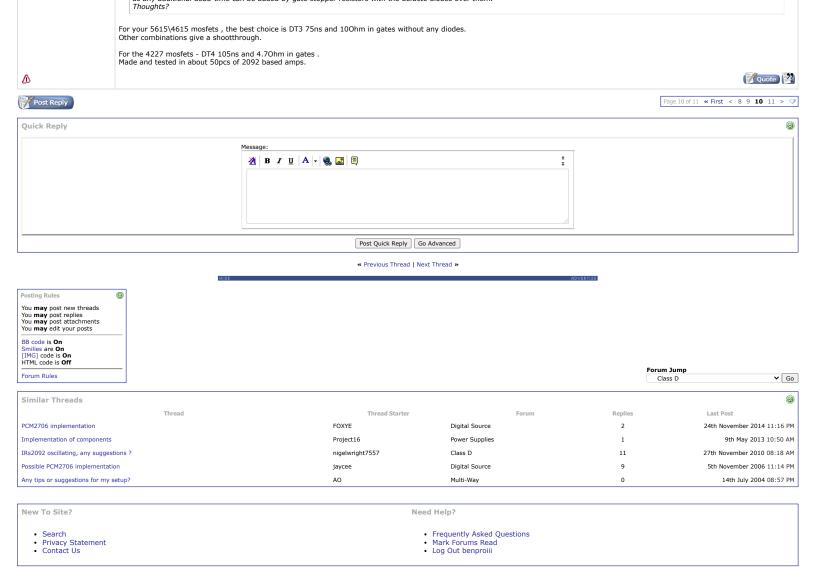
Originally Posted by SSassen 55 the DT2 option, 45ns, seems to be the most used setting, resulting in 8.2kOhm for R14 and 3.3kOhm for R13.

8.2k\3.3k results in DT3 option 75ns

Quote:

Originally Posted by SSassen D

#100



as any additional dead-time can be added by gate stopper resistors with the defacto diodes over them.

All times are GMT. The time now is 06:04 PM.

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